MAAM-007796



Low Noise FTTx Amplifier 50 - 1000 MHz

Rev. V3

Features

- Low Distortion
- Low Noise Figure
- Lead-Free 4 mm 20-Lead PQFN Package
- Halogen-Free "Green" Mold Compound
- 260°C Reflow Compatible

Description

M/A-COM's MAAM-007796 is a GaAs PHEMT MMIC amplifier in a lead-free 4 mm 20-lead PQFN package. The Amplifier is designed to meet the high gain, high linearity and low noise requirements of FTTx receivers.

Ordering Information 1,2

Part Number	Package
MAAM-007796-TR1000	1000 piece reel
MAAM-007796-TR3000	3000 piece reel
MAAM-007796-000SMB	Sample Test Board

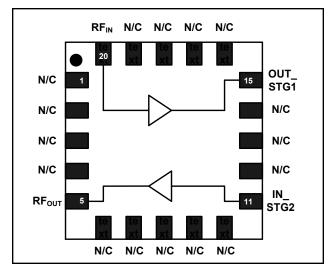
- 1. Reference Application Note M513 for reel size information.
- 2. All sample boards include 5 loose parts.

Absolute Maximum Ratings 3,4

Parameter	Absolute Maximum
Input Power	+5 dBm
Operating Voltage	+10 volts
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

- Exceeding any one or combination of these limits may cause permanent damage to this device.
- M/A-COM does not recommend sustained operation near these survivability limits.

Functional Schematic



Pin Configuration ⁵

Pin No.	Pin Name	Description	
1	N/C	No Connection	
2	N/C	No Connection	
3	N/C	No Connection	
4	N/C	No Connection	
5	RF _{OUT}	RF Output	
6	N/C	No Connection	
7	N/C	No Connection	
8	N/C	No Connection	
9	N/C	No Connection	
10	N/C	No Connection	
11	IN_STG2	STAGE 2 RF Input	
12	N/C	No Connection	
13	N/C	No Connection	
14	N/C	No Connection	
15	OUT_STG1	STAGE 1 RF Output	
16	N/C	No Connection	
17	N/C	No Connection	
18	N/C	No Connection	
19	N/C	No Connection	
20	RF _{IN}	RF Input	

The exposed pad centered on the package bottom must be connected to RF and DC ground.

^{*} Restrictions on Hazardous Substances, European Union Directive 2002/95/EC.

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

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 Visit www.macomtech.com for additional data sheets and product information.



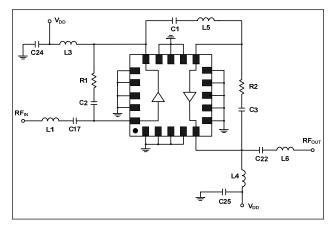
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Electrical Specifications: $T_A = 25$ °C, Freq: 50 - 1000 MHz, $V_{DD} = +5$ Volts, $Z_0 = 75$ Ω

Parameter	Test Conditions	Units	Min.	Тур.	Max.
Gain	RF _{IN} to RF _{OUT}	dB	20	21	22
Gain Flatness	RF _{IN} to RF _{OUT}	dB	0	0.4	0.7
Noise Figure	RF _{IN} to RF _{OUT}	dB	3	3.8	5.3
Input Return Loss	RF _{IN}	dB	-	15	-
Output Return Loss	RF _{OUT}	dB	-	15	-
Output IP3	Two tones at 397 & 403 MHz, +5 dBm output per tone	dBm	-	35	-
Composite Triple Beat, CTB	132 Channels, +20 dBmV/Channel at the Output	dBc	-	-70	-
Composite Second Order, CSO	132 Channels, +20 dBmV/Channel at the Output	dBc	-	-70	-68
Cross modulation	132 Channels, +20 dBmV/Channel at the Output	dBc	-	-70	-
P1dB	400 MHz	dBm	-	20	-
I _{DD}	V _{DD} = +5 Volts	mA	140	160	180

Test Circuit Schematic



Off-Chip Component Values ⁶

Component	Value	Package
C1-C3, C17, C22,C24-C25	0.01 μF	0402
L1	5.6 nH	0402
L3, L4	1.0 µH	1210
L5	3.9 nH	0402
L6	4.7 nH	0402
R1, R2	300 Ω	0402

L3 and L4 supplied from EPCOS, part number B82422A1102K100.

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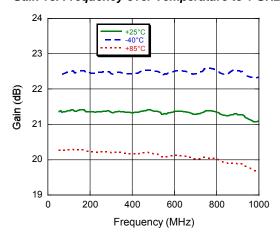


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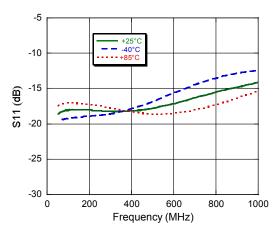
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Typical Performance Curves

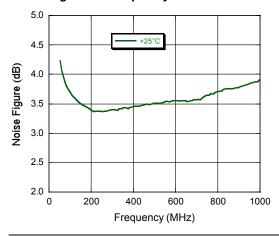
Gain vs. Frequency over Temperature to 1 GHz



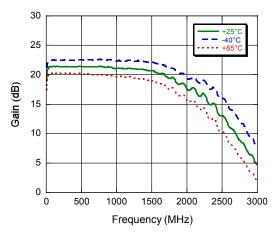
Input Return Loss vs. Frequency over Temperature



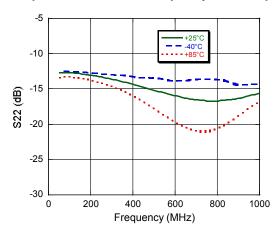
Noise Figure vs. Frequency



Gain vs. Frequency over Temperature to 3 GHz



Output Return Loss vs. Frequency over Temperature



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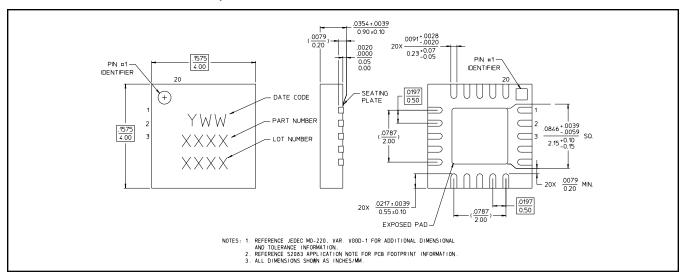
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Lead-Free 4 mm 20-Lead PQFN[†]



Reference Application Note S2083 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 1 requirements. Plating is 100% matte tin over copper.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Arsenide Integrated Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

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